

## General Description

The MY5D03C is the highest performance trench N-ch MOSFETs with extreme high ell density, which provide excellent  $R_{DS(on)}$  and gate charge for most of the small power switching and load switch applications.

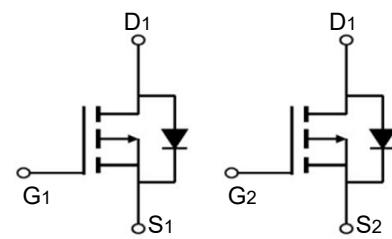
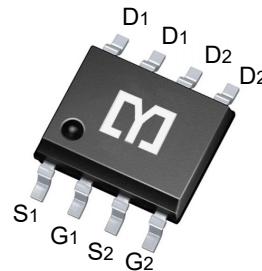


## Features

$V_{DSS}$	-30	V
$I_D$	-5	A
$R_{DS(ON)}(\text{at } V_{GS}=4.5V)$	<43	$m\Omega$
$R_{DS(ON)}(\text{at } V_{GS}=2.5V)$	<68	$m\Omega$

## Application

- Battery protection
- Load switch
- Uninterruptible power supply



## Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY5D03C	SOP-8	5D03C	3000

## Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current-Continuous	$I_D$	-5.3	A
Drain Current-Pulsed (Note 1)	$I_{DM}$	-20	A
Maximum Power Dissipation	$P_D$	2.6	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	$^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	49	$^\circ\text{C}/\text{W}$

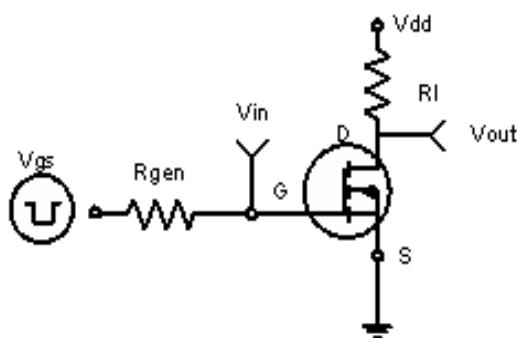
**Electrical Characteristics ( $T_A=25^\circ\text{C}$ , unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-30	-33	-	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=-24\text{V}, V_{\text{GS}}=0\text{V}$	-	-	-1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm100$	nA
<b>On Characteristics</b> (Note 3)						
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-1	-1.6	-3	V
Drain-Source On-State Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-5.3\text{A}$	-	43	49	m
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-4.2\text{A}$	-	68	100	m
Forward Transconductance	$g_{\text{FS}}$	$V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-4.5\text{A}$	4	7	-	S
<b>Dynamic Characteristics</b> (Note 4)						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=-15\text{V}, V_{\text{GS}}=0\text{V}, F=1.0\text{MHz}$	-	540	-	PF
Output Capacitance	$C_{\text{oss}}$		-	150	-	PF
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	75	-	PF
<b>Switching Characteristics</b> (Note 4)						
Turn-on Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=-15\text{V}, I_{\text{D}}=-1\text{A}, V_{\text{GS}}=-10\text{V}, R_{\text{GEN}}=6$	-	8	-	nS
Turn-on Rise Time	$t_{\text{r}}$		-	14	-	nS
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	18	-	nS
Turn-Off Fall Time	$t_{\text{f}}$		-	10	-	nS
Total Gate Charge	$Q_{\text{g}}$	$V_{\text{DS}}=-15\text{V}, I_{\text{D}}=-5.3\text{A}, V_{\text{GS}}=-10\text{V}$	-	12	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	2.4	-	nC
Gate-Drain Charge	$Q_{\text{gd}}$		-	3.2	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{s}}=-5.3\text{A}$	-	-	-1.2	V

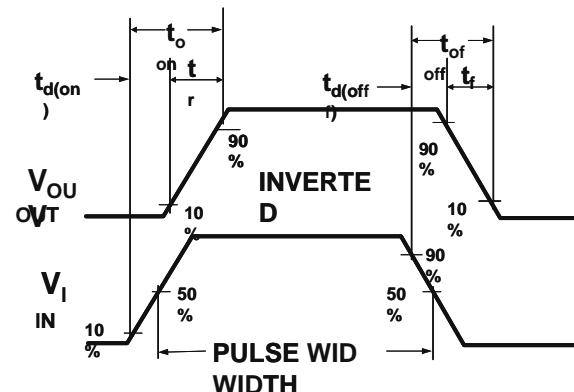
**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

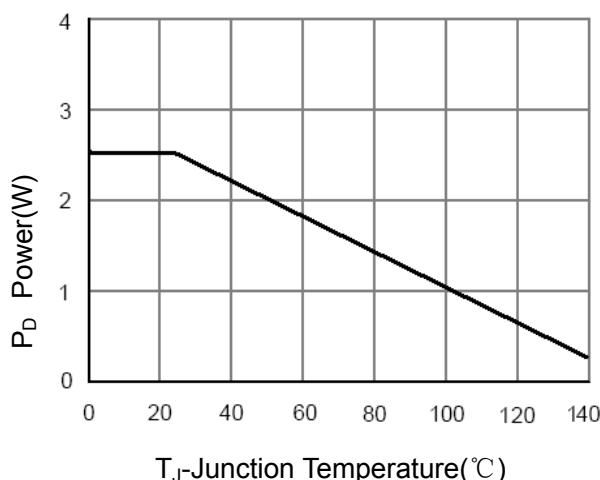
### Typical Electrical and Thermal Characteristics



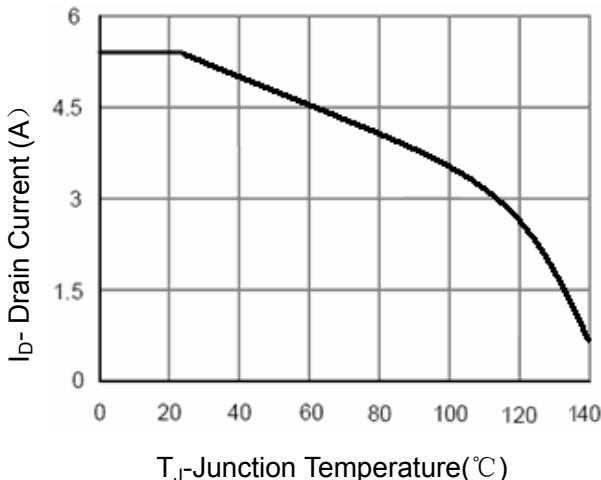
**Figure 1:Switching Test Circuit**



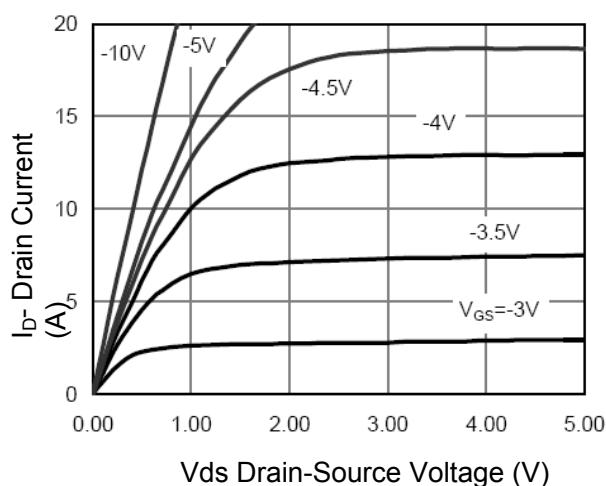
**Figure 2:Switching Waveforms**



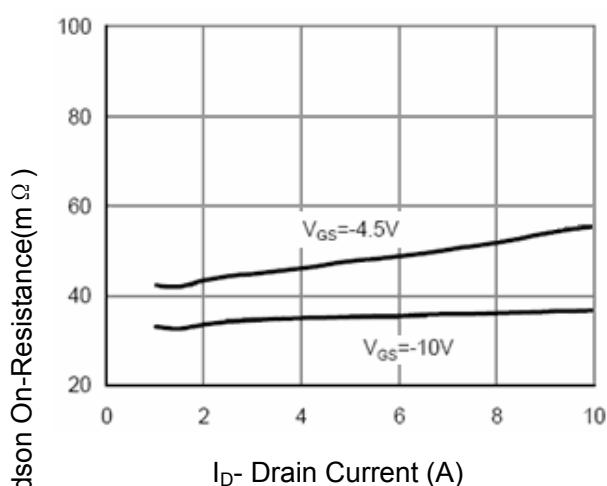
**Figure 3 Power Dissipation**



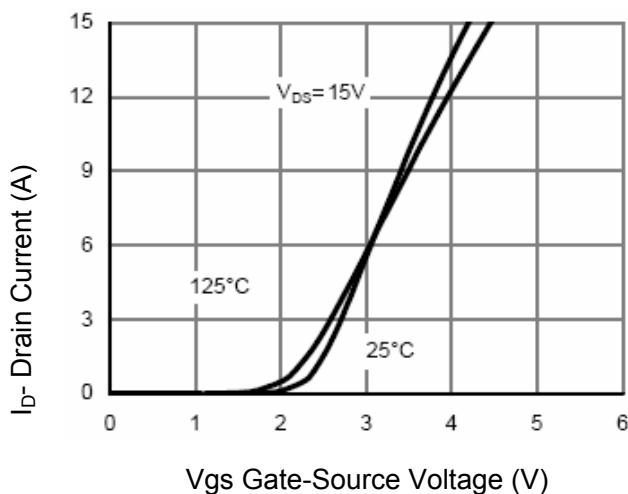
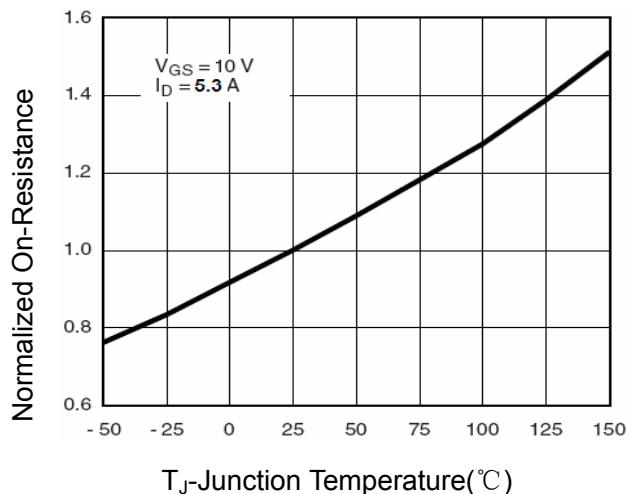
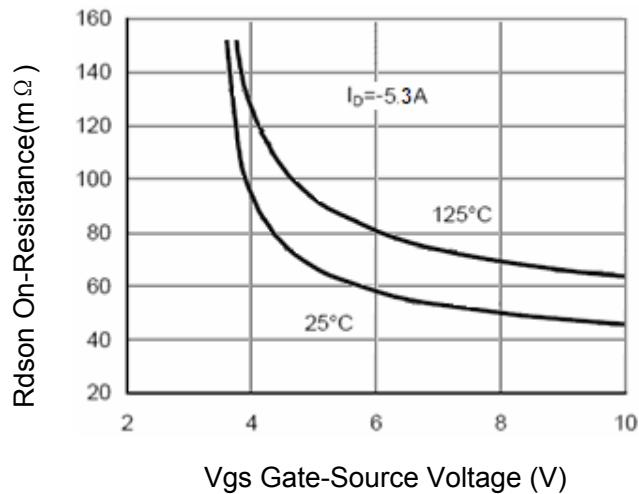
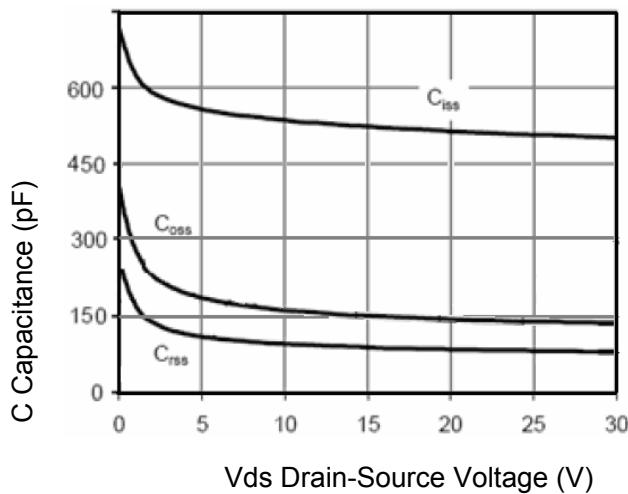
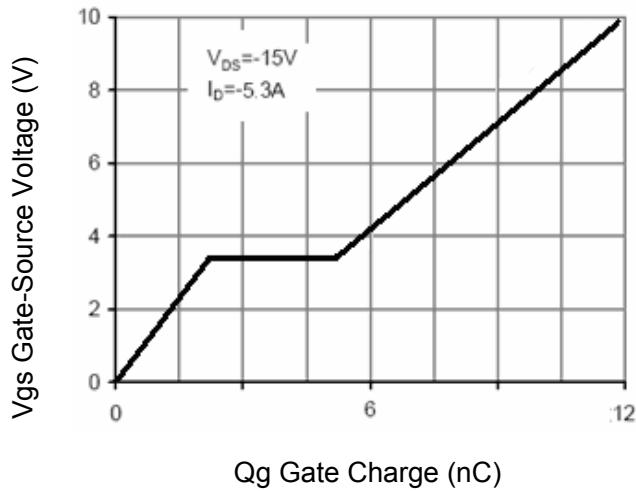
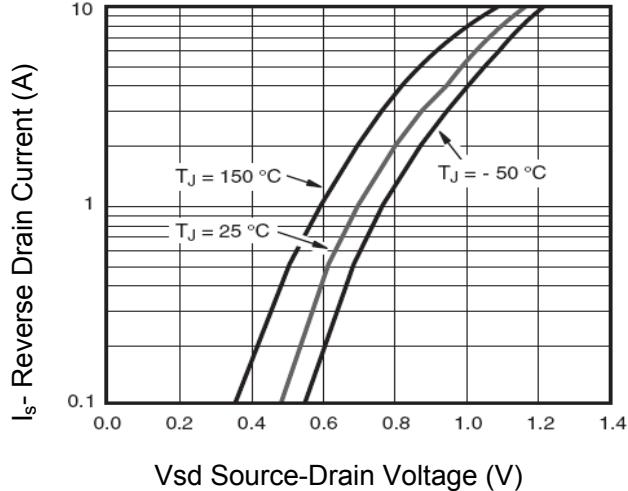
**Figure 4 Drain Current**

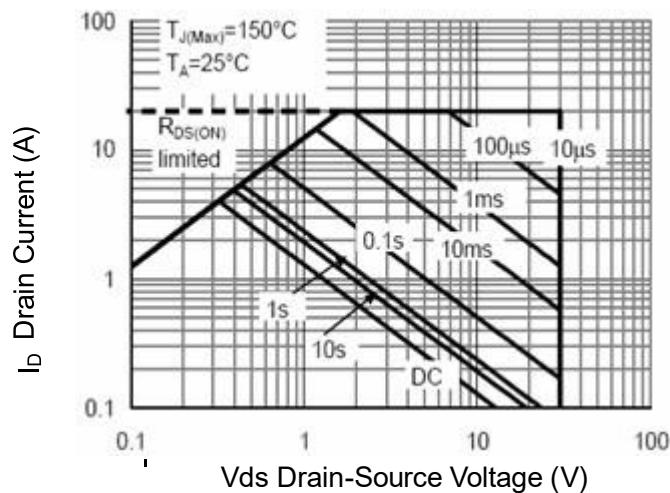
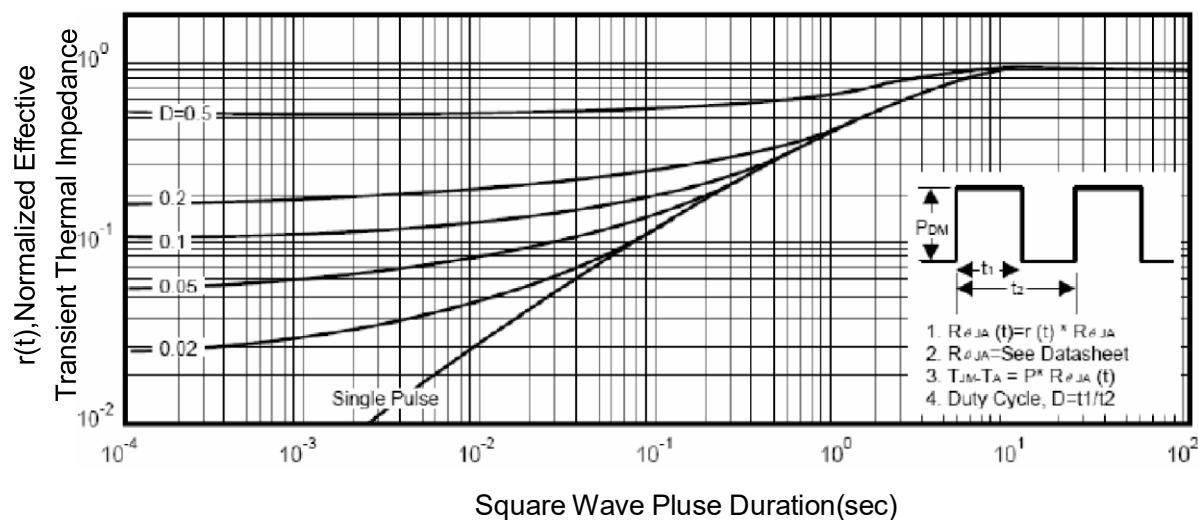


**Figure 5 Output Characteristics**

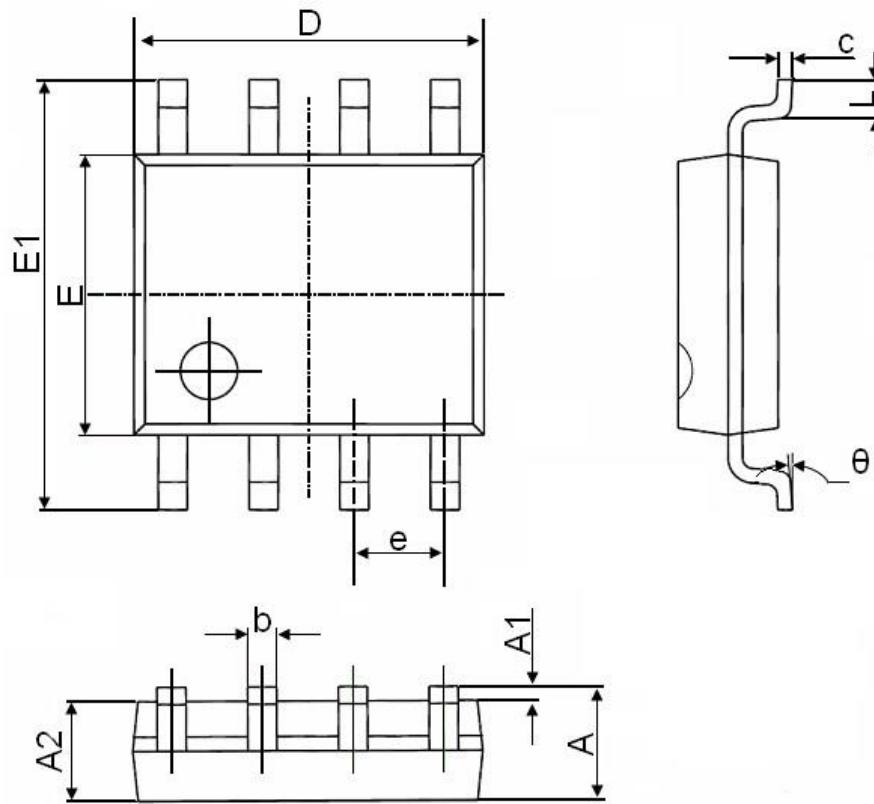


**Figure 6 Drain-Source On-Resistance**

**Figure 7 Transfer Characteristics****Figure 8 Drain-Source On-Resistance****Figure 9  $R_{DS(on)}$  vs  $V_{GS}$** **Figure 10 Capacitance vs  $V_{DS}$** **Figure 11 Gate Charge****Figure 12 Source-Drain Diode Forward**

**Figure 13 Safe Operation Area****Figure 14 Normalized Maximum Transient Thermal Impedance**

## Package Mechanical Data-SOP-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050